

AN-XA7XXXX-X Series HF SMD TCXO/VCTCXO Ultra Low Phase Noise

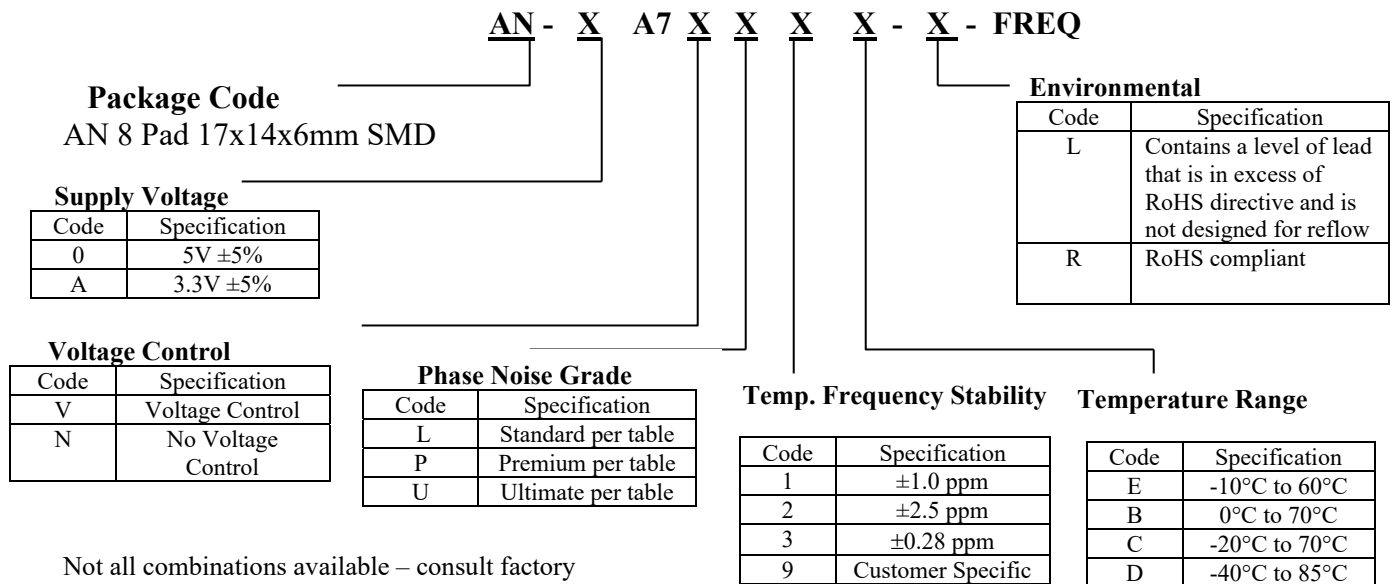
Rev. R

Description: The AN-XA7XXXX Series of SMD temperature compensated crystal oscillators (TCXO), provides High Frequency with excellent temperature stability, extremely low phase noise and jitter with Sine-wave output in a small surface mount FR4 based package.

Features

- Small, Low Profile SMD Package
- Very Low Phase Jitter and Phase Noise
- Excellent Frequency Stability
- Frequency – up to 250 MHz
- No Multiplication – no sub-harmonics
- Stratum3 available
- COTS/Dual use

Creating a Part Number



AN-XA7XXXX-X Series

Rev. R

(1)

Specifications

Parameter	Symb	Condition	Min	Typ	Max	Unit	Note
Electrical							
Frequency Range	F	Sine-wave	10		250	MHz	
Input Voltage	Vcc		3.135 4.75	3.30 5.0	3.465 5.25	V	A 0
Input Current	Icc	Sine			40	mA	@100MHz, 3.3V
Frequency Stab.	$\Delta F/F$	Overall, available			± 4.6		20 years
Frequency Stability	$\Delta F/F$	vs. Temperature vs. Vcc aging		± 0.5 ± 0.1 ± 1 ± 2.5 ± 3.5	± 1	ppm ppm/V ppm/year ppm ppm	See chart First Year 7 years 10 years
Calibration	$\Delta F/F$	As shipped, 25°C		± 0.5	± 1	ppm	
Load		Sine	Internally AC-coupled 50 Ohm				
Output power ⁽²⁾	P	Sine-wave Into 50 Ohms	0 4	3 7		dBm	3.3V 5.0V
Start up time	Ts			2	100	ms	
Phase Jitter		1 σ		0.4 0.2	1 0.4	ps	100Hz to 20MHz 12KHz to 20MHz
Subharmonics						none	
Spurious					-60	dBc	
Harmonics		Sine-wave		-30	-25	dBc	
SSB Phase Noise		@10Hz @100 Hz @1 KHz @10 KHz @100 KHz		-80 -110 -140 -155 -160		dBc/Hz	@100MHz, Grade L
SSB Phase Noise		@10Hz @100 Hz @1 KHz @10 KHz @100 KHz		-90 -120 -150 -160 -165			@100MHz, Grade P
SSB Phase Noise		@10Hz @100 Hz @1 KHz @10 KHz @100 KHz		-95 -125 -155 -165 -170			@100MHz, Grade U
SSB Phase Noise		@10Hz @100 Hz @1 KHz @10 KHz @100 KHz		-105 -135 -150 -160 -165		dBc/Hz	@20 MHz
Input Impedance				>10K Ohm			
Control voltage	Vc		0		3.0	V	
Modulation bandwidth	MB				1.5	Hz	
Deviation	$\Delta F/F$	Vc=0V to 3.3V, 25°C	± 5	± 7		ppm	

Note 1) All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load
 2) Higher output power available – consult factory (current consumption may increase)

Absolute Maximum Ratings

Parameter	Symb	Condition	Min	Typ	Max	Unit	Note
Input Break Down Voltage	Vcc		-0.5		5.5	V	
Storage temp.	Ts		-40		105	° C	
Contr. Voltage	Vc		-1		9	V	

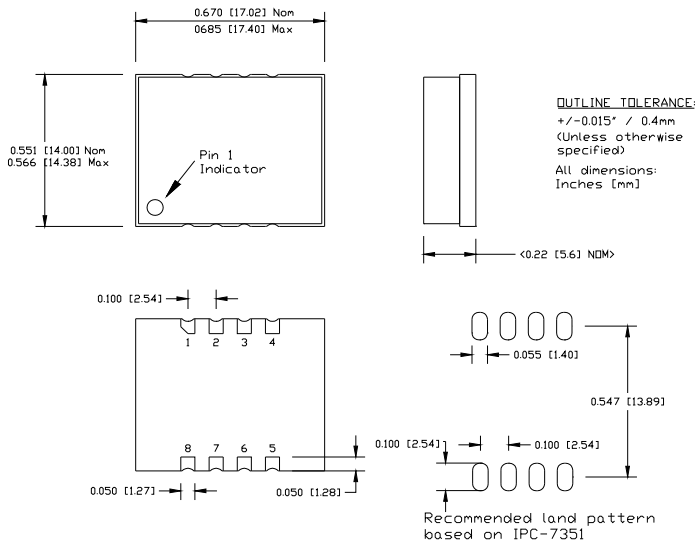


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Environmental and Mechanical

Operating temp. range	0°C to 70°C , -40°C to 85°C, see chart, page 1
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. E
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Soldering Conditions	See MAX reflow profile; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.
Hermetic Seal	Leak rate less than 1×10^{-8} atm.cc/s of helium (crystal only)



Electrical Connections

Pin out	Pin 1=Vcc; Pin 2=Do Not Connect; Pin 3=GND; Pin 4=GND; Pin 5=Output; Pin 6= Optional Voltage Control; Pin 7 & 8= Do Not Connect
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Maximum solder reflow profile

